# Silicon Carbide Schottky Diode

# 650 V, 20 A

# **Description**

Silicon Carbide (SiC) Schottky Diodes use a completely new technology that provides superior switching performance and higher reliability compared to Silicon. No reverse recovery current, temperature independent switching characteristics, and excellent thermal performance sets Silicon Carbide as the next generation of power semiconductor. System benefits include highest efficiency, faster operating frequency, increased power density, reduced EMI, and reduced system size & cost.

### **Features**

- Max Junction Temperature 175°C
- Avalanche Rated 94 mJ
- High Surge Current Capacity
- Positive Temperature Coefficient
- Ease of Paralleling
- No Reverse Recovery/No Forward Recovery
- AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

# **Applications**

- Automotive HEV-EV Onboard Chargers
- Automotive HEV-EV DC-DC Converters

# MOSFET MAXIMUM RATINGS (T<sub>C</sub> = 25°C unless otherwise noted)

Symbol	Parameter	Unit	Ratings	Unit
$V_{RRM}$	Peak Repetitive Reverse Voltage		650	V
E <sub>AS</sub>	Single Pulse Avalanche Energy (Note 1)		94	mJ
I <sub>F</sub>	Continuous Rectified Forward	@ T <sub>C</sub> < 141°C	20	20 A
	Current	@ T <sub>C</sub> < 135°C	22.3	
I <sub>F, Max</sub>	Non-Repetitive Peak Forward	T <sub>C</sub> = 25°C, 10 μs	889	Α
	Surge Current	T <sub>C</sub> = 150°C, 10 μs	861	
I <sub>F, SM</sub>	Non-Repetitive Forward Surge Current T <sub>C</sub> = 25°C	Half-Sine Pulse, t <sub>p</sub> = 8.3 ms	84	A
Ptot	Power Dissipation	T <sub>C</sub> = 25°C	148	W
		T <sub>C</sub> = 150°C	25	
T <sub>J</sub> ,T <sub>STG</sub>	Operating and Storage Temperature Range		–55 to +175	°C
	TO247 Mounting Torque, M3 Screw		60	Ncm

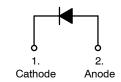
Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1.  $E_{AS}$  of 94 mJ is based on starting  $T_J = 25^{\circ}C$ , L = 0.5 mH,  $I_{AS} = 19.4$  A, V = 50 V.



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**Schottky Diode** 



TO-247-2LD CASE 340DA

### **MARKING DIAGRAM**



\$Y = ON Semiconductor Logo &Z = Assembly Plant Code &3 = Numeric Date Code &K = Lot Code FFSH2065B = Specific Device Code

#### **ORDERING INFORMATION**

See detailed ordering and shipping information on page 2 of this data sheet.

# THERMAL CHARACTERISTICS

Symbol	Parameter	Ratings	Unit
$R_{ heta JC}$	Thermal Resistance, Junction to Case, Max	1.01	°C/W

# **ELECTRICAL CHARACTERISTICS** ( $T_C = 25^{\circ}C$ unless otherwise noted)

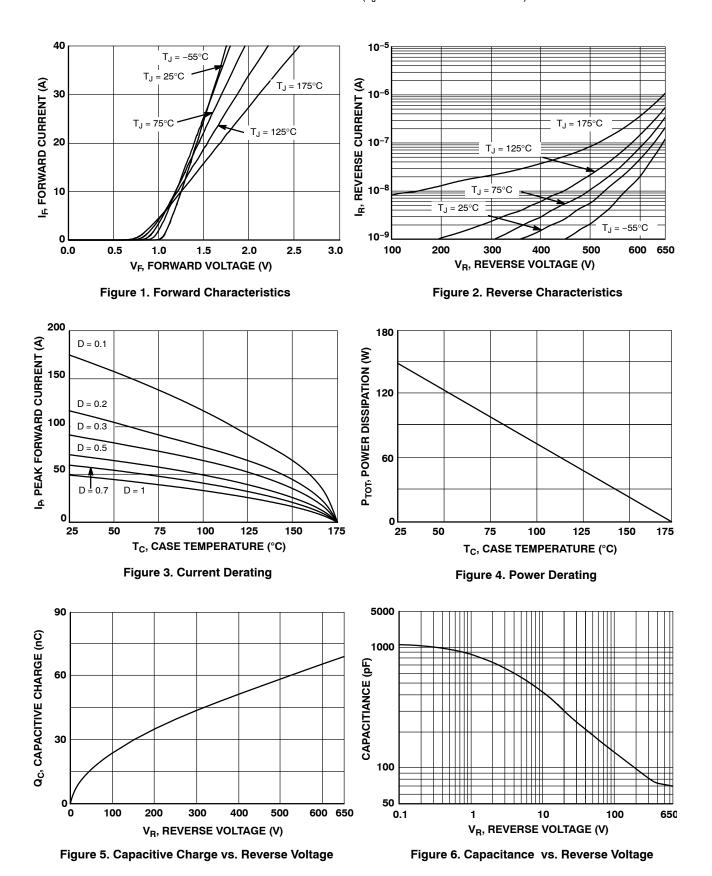
Symbol	Parameter	Test Conditions	Min	Тур	Max	Unit
V <sub>F</sub>	Forward Voltage	I <sub>F</sub> = 20 A, T <sub>C</sub> = 25°C	=	1.38	1.7	V
		I <sub>F</sub> = 20 A, T <sub>C</sub> = 125°C	=	1.6	2.0	
		I <sub>F</sub> = 20 A, T <sub>C</sub> = 175°C	-	1.72	2.4	
I <sub>R</sub>	Reverse Current	V <sub>R</sub> = 650 V, T <sub>C</sub> = 25°C	-	0.5	40	μΑ
		V <sub>R</sub> = 650 V, T <sub>C</sub> = 125°C	-	1	80	]
		V <sub>R</sub> = 650 V, T <sub>C</sub> = 175°C	-	2	160	]
Q <sub>C</sub>	Total Capacitive Charge	V = 400 V	-	51	-	nC
С	Total Capacitance	V <sub>R</sub> = 1 V, f = 100 kHz	-	866	-	pF
		V <sub>R</sub> = 300 V, f = 100 kHz	_	80	_	
		V <sub>R</sub> = 600 V, f = 100 kHz	_	70	_	

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

# PACKAGE MARKING AND ORDERING INFORMATION

Part Number	Top Mark	Package	Shipping
FFSH2065B-F085	FFSH2065B	TO-247-2LD (Pb-Free/Halogen Free)	30 Units/Tube

# TYPICAL CHARACTERISTICS (T<sub>J</sub> = 25°C unless otherwise noted)



# $\textbf{TYPICAL CHARACTERISTICS} \ (T_C = 25^{\circ}\text{C unless otherwise noted}) \ (\text{continued})$

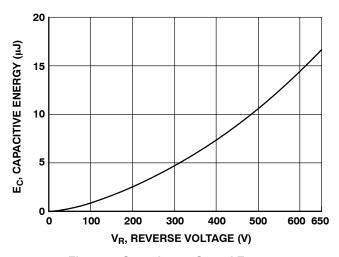


Figure 7. Capacitance Stored Energy

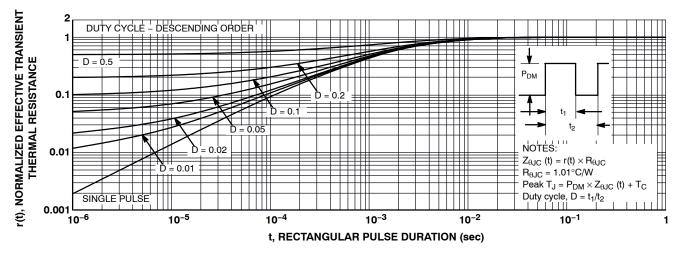


Figure 8. Junction-to-Case Transient Thermal Response Curve

# **TEST CIRCUIT AND WAVEFORMS**

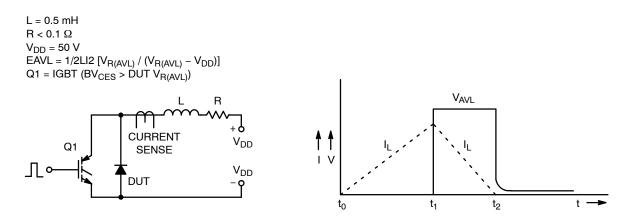
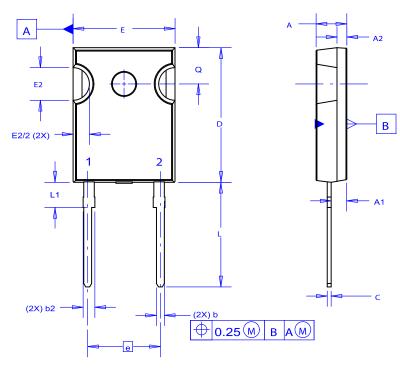


Figure 9. Unclamped Inductive Switching Test Circuit & Waveform

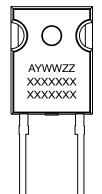
# TO-247-2LD CASE 340DA ISSUE A





- A. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.
- B. ALL DIMENSIONS ARE IN MILLIMETERS.
- C. DRAWING CONFORMS TO ASME Y14.5 2009.
- D. DIMENSION A1 TO BE MEASURED IN THE REGION DEFINED BY L1.
- E. LEAD FINISH IS UNCONTROLLED IN THE REGION DEFINED BY L1.

# GENERIC MARKING DIAGRAM\*



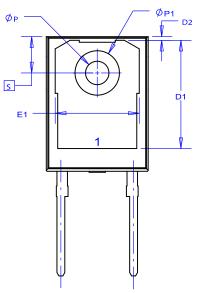
XXXXX = Specific Device Code

A = Assembly Location Y = Year

WW = Work Week
ZZ = Assembly Lot Code

\*This information is generic. Please refer to device data sheet for actual part marking. Pb—Free indicator, "G" or microdot " •", may or may not be present. Some products may not follow the Generic Marking.

# DATE 27 FEB 2019



DIM	MILLIMETERS			
DIM	MIN	NOM	MAX	
Α	4.58	4.70	4.82	
<b>A</b> 1	2.20	2.40	2.60	
A2	1.40	1.50	1.60	
b	1.17	1.26	1.35	
b2	1.53	1.65	1.77	
С	0.51	0.61	0.71	
D	20.32	20.57	20.82	
D1	13.08	~	~	
D2	0.51	0.93	1.35	
Е	15.37	15.62	15.87	
E1	12.81	~	~	
E2	4.96	5.08	5.20	
е	?	11.12	?	
L	15.75	16.00	16.25	
L1	3.69	3.81	3.93	
ØΡ	3.51	3.58	3.65	
ØP1	6.60	6.80	7.00	
Q	5.34	5.46	5.58	
S	5.34	5.46	5.58	

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DESCRIPTION:	TO-247-2LD		PAGE 1 OF 1	

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